TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX374F, TC74LCX374FK

Low-Voltage Octal D-Type Flip-Flop with 5-V Tolerant Inputs and Outputs

The TC74LCX374 is a high-performance CMOS octal D-type flip-flop. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

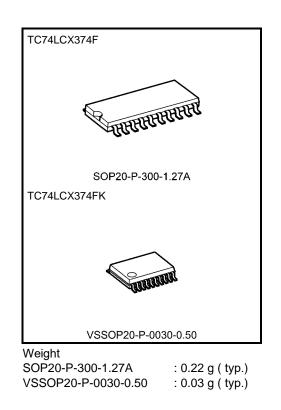
The device is designed for low-voltage (3.3 V) V_{CC} applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 8 bit D-type flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge.

Features

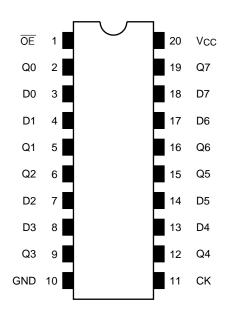
- Low-voltage operation: VCC = 1.65 to 3.6 V
- High-speed operation: $t_{pd} = 8.5 \text{ ns} (\text{max}) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Available in JEITA SOP, VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 374 type



Note: The Electrical Characteristics of V_{CC} = 1.8 ± 0.15 V is only applicable for products which manufactured from January 2009 onward.

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Pin Assignment (top view)



Truth Table

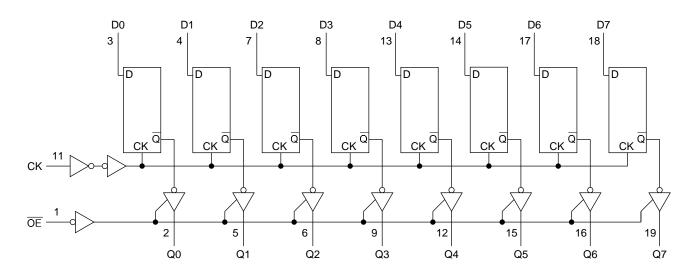
	Outputo		
ŌĒ	СК	D	Outputs
Н	Х	Х	Z
L		Х	Qn
L		L	L
L		Н	Н

X: Don't care

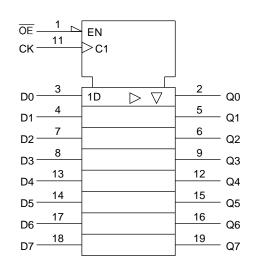
Z: High impedance

Qn: No change

System Diagram



IEC Logic Symbol



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 2)	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	Ік	-50	mA
Output diode current	ЮК	±50 (Note 4)	mA
DC output current	Ιουτ	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	ICC/IGND	±100	mA
Storage temperature	T _{stg}	–65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: Output in OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Deview eventhe visite ere	Maa	1.65 to 3.6		
Power supply voltage	Vcc	1.5 to 3.6 (Note 2)	V	
Input voltage	Vin	0 to 5.5	V	
		0 to 5.5 (Note 3)	V	
Output voltage	Vout	0 to VCC (Note 4)		
Output ourroot	Іон/Іог	±24 (Note 5)	m (
Output current	IOH/IOL	±12 (Note 6)	mA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: VCC = 3.0 to 3.6 V $\,$

Note 6: VCC = 2.7 to 3.0 V

Note 7: VIN = 0.8 to 2.0 V, VCC = 3.0 V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Characteristics Symbol Test Condition		lition	Vcc (V)	Min	Max	Unit								
					1.65 to 2.3	V _{CC} × 0.9								
	H-level	VIH	_	_		1.7								
					2.7 to 3.6	2.0								
Input voltage					1.65 to 2.3		Vcc × 0.1	V						
	L-level	VIL	—		2.3 to 2.7		0.7							
					2.7 to 3.6	_	0.8							
				IOH = -100 μA	1.65 to 3.6	Vcc-0.2	_							
				I _{OH} = -4 mA	1.65	1.05	_							
	H-level	Vou	Vin = Vih or Vil	Iон = -8 mA	2.3	1.7	_	- V						
	n-ievei	Vон	VIN = VIH OF VIL	IOH = -12 mA	2.7	2.2	_							
				I _{OH} = -18 mA	3.0	2.4	_							
Output voltage				Iон = -24 mA	3.0	2.2	_							
Output voltage			VIN = VIH or VIL	$I_{OL} = 100 \ \mu A$	1.65 to 3.6		0.2							
				$I_{OL} = 4 \text{ mA}$	1.65		0.45							
	L-level	Vo		IOL = 8 mA	2.3		0.7							
	L-level	Vol		$I_{OL} = 12 \text{ mA}$	2.7		0.4							
						I _{OL} = 16 mA	3.0		0.4					
										I _{OL} = 24 mA	3.0		0.55	
Input leakage current		l _{IN}	$V_{IN} = 0$ to 5.5 V		1.65 to 3.6		±5.0	μA						
3-state output OFF state current		I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$		1.65 to 3.6	_	±5.0	μΑ						
Power-off leakage cur	-off leakage current IOFF VIN/VOUT = 5.5 V		0		10.0	μA								
	ot		V _{IN} = V _{CC} or GND		1.65 to 3.6		10.0							
Quiescent supply curr	ent	Icc	$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5$	V	1.65 to 3.6		±10.0	μA						
Increase in ICC per inp	out	∆lcc	VIH = VCC – 0.6 V (per 1 input)		2.7 to 3.6	_	500							

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Characteristics Symbol Test Condition		Min	Min Max		
Characteristics	Symbol	Test Condition	V _{CC} (V)	IVIITI	IVIAX	Unit
			1.8 ± 0.15	50	_	MHz
	f _{max}	Figure 1, Figure 2	2.5 ± 0.2	100	_	
Maximum clock frequency	imax		2.7	100	_	
			$\textbf{3.3}\pm\textbf{0.3}$	150	_	
			1.8 ± 0.15	—	30.0	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2		10.5	ns
(CK-Q)	tpHL		2.7		9.5	115
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	
			1.8 ± 0.15		34.0	
Output anable time	tpZL		2.5 ± 0.2		17.0	ns
Output enable time	t _P ZH	Figure 1, Figure 3	2.7		9.5	
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	
			1.8 ± 0.15	_	32.0	ns
Quitaut diachla tima	tpLZ tpHZ	Figure 1, Figure 3	2.5 ± 0.2	_	16.0	
Output disable time			2.7	_	8.5	
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.5	
		Figure 1, Figure 2	1.8 ± 0.15	12.0	_	ns
Minimum pulse width	t _w (H)		2.5 ± 0.2	6.0		
(CK)	t _w (L)		2.7	4.0		
			$\textbf{3.3}\pm\textbf{0.3}$	3.3		
			1.8 ± 0.15	10.0		ns
Minimum optun timo			2.5 ± 0.2	5.0	_	
Minimum setup time	ts	Figure 1, Figure 2	2.7	2.5		
			$\textbf{3.3}\pm\textbf{0.3}$	2.5	_	
			1.8 ± 0.15	1.5	_	ns
Minimum hold time	1		2.5 ± 0.2	1.5	_	
	t _h	Figure 1, Figure 2	2.7	1.5		
			$\textbf{3.3}\pm\textbf{0.3}$	1.5	_	
	t _{osLH}		2.7	_	_	
Output to output skew	t _{osHL}	(Note)		_	1.0	ns

Note: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

Dynamic Switching Characteristics (Ta = 25°C, input: tr = tf = 2.5 ns, CL = 50 pF, RL = 500 Ω)

Characteristics	Symbol	Test Condition	Vcc (V)	Тур.	Unit
Quiet output maximum dynamic VOL	Volp	$V_{IH} = 3.3 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic $V_{\mbox{OL}}$	Volv	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

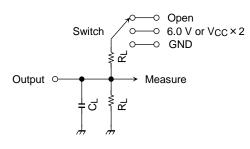
Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	CIN	_	3.3	7	pF
Output capacitance	Соит	—	3.3	8	pF
Power dissipation capacitance	CPD	f _{IN} = 10 MHz (Note) 3.3	25	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

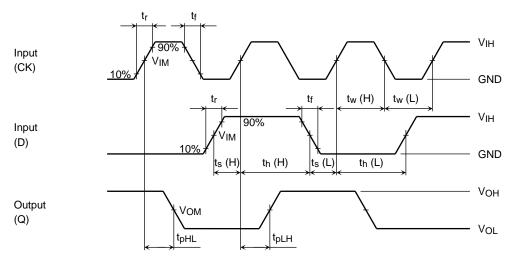
Average operating current can be obtained by the equation: $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC/8 (per bit)$

AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
	6.0 V	@ V _{CC} =3.3±0.3V @ V _{CC} =2.7V	
tpLZ, tpZL	Vcc×2	<pre>@ V_{CC} =2.5±0.2V @ V_{CC} =1.8±0.15V</pre>	
tpHZ, tpZH	GND		

Figure 1



AC Waveform

Figure 2 t_{pLH}, t_{pHL}, t_w, t_s, t_h



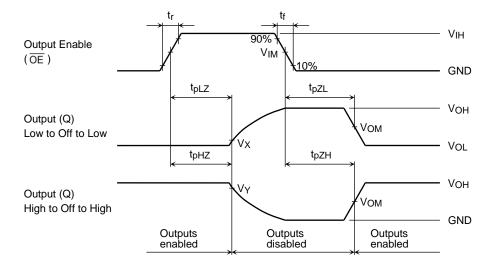


Figure 3 t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}

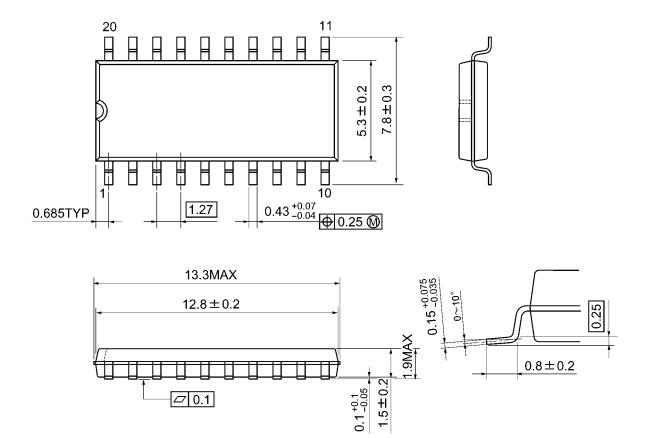
		Vcc				
	Symbol	3.3 ± 0.3 V 2.7 V	$2.5\pm0.2~\text{V}$	$1.8\pm0.15~V$		
Input	VIH	2.7 V	V _{CC}	V _{CC}		
	VIM	1.5 V	V _{CC} /2	V _{CC} /2		
	t _r , t _f	2.5 ns	2.0 ns	2.0 ns		
Output	Vom	1.5 V	V _{OH} /2	V _{OH} /2		
	Vx	Vol +0.3 V	Vol +0.15 V	V _{OL} +0.15 V		
	Vy	V _{OH} -0.3 V	V _{OH} -0.15 V	Voн -0.15 V		
Load	CL	50 pF	30 pF	30 pF		
	RL	500 Ω	500 Ω	1 kΩ		



Package Dimensions

SOP20-P-300-1.27A

Unit: mm



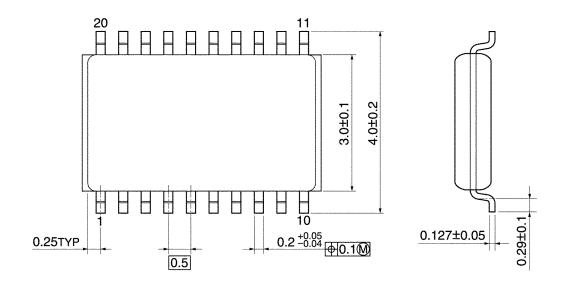
Weight: 0.22 g (typ.)

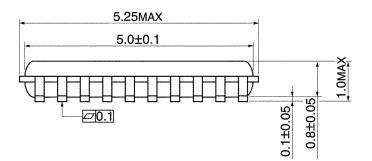


Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm





Weight: 0.03 g (typ.)

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